SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 4334, REV. -

HERMETIC POWER MOSFET N-CHANNEL

FEATURES:

- 100 Volt, 75A, 0.02 Ohm, MOSFET
- Isolated Hermetic Metal Package
- Fast intrinsic Rectifier
- Low R_{DS (on)}
- Low package inductance-easy to drive and protect

MAXIMUM RATINGS

ALL RATINGS ARE AT T_o = 25°C UNLESS OTHERWISE SPECIFIED.

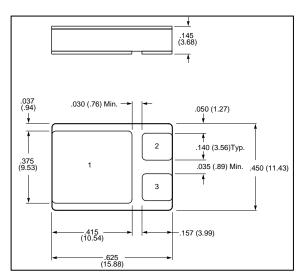
RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	V _{GS}	-	-	±20	Volts
ON-STATE DRAIN CURRENT @ T _C = 25°C	I _{D (on)}	-	-	75	Amps
PULSED DRAIN CURRENT @ $T_c = 25^{\circ}C$	I _{DM}	-	-	300	Amps
OPERATING AND STORAGE TEMPERATURE	T _{OP} /T _{STG}	-55	-	+150	°C
THERMAL RESISTANCE, JUNCTION TO CASE	R _{thJC}	-	-	0.32	°C/W
TOTAL DEVICE DISSIPATION @ T _C = 25°C	PD	-	-	390	Watts

ELECTRICAL CHARACTERISTICS

RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
DRAIN TO SOURCE BREAKDOWN VOLTAGE	BV _{DSS}	100	-	-	Volts
$V_{GS} = 0V, I_{D} = 250 \ \mu A$					
STATIC DRAIN TO SOURCE ON STATE RESISTANCE		-	-		
$V_{GS} = 10V, I_D = 37.5A$	R _{DS(ON)}			0.025	Ω
GATE THRESHOLD VOLTAGE $V_{DS} = V_{GS}$, $I_D = 250 \mu A$	V _{GS(th)}	2.0	-	4.0	Volts
FORWARD TRANSCONDUCTANCE	g _{fs}	25	30	-	S(1/Ω)
V _{DS} = 10V, I _D = 37.5A					
ZERO GATE VOLTAGE DRAIN CURRENT		-			
$V_{DS} = 0.8 x Max$. Rating, $V_{GS} = 0 V$	I _{DSS}		-	200	μA
$V_{DS} = 0.8$ xMax. Rating, $V_{GS} = 0$ V, $T_{J} = 125$ °C			-	1.0	mA
GATE TO SOURCE LEAKAGE FORWARD $V_{GS} = 20V$	I _{GSS}	-	-	100	nA
GATE TO SOURCE LEAKAGE REVERSE V _{GS} = -20V				-100	
TURN ON DELAY TIME $V_{DS} = 0.5V$,	t _{d(ON)}	-	40	60	
RISE TIME $I_D = 37.5A$,	tr		60	110	nsec
TURN OFF DELAY TIME $R_G = 2.0\Omega$,	t _{d(OFF)}		100	140	
FALL TIME $V_{GS} = 10V$	t _f		30	60	
DIODE FORWARD VOLTAGE $T_c = 25^{\circ}C, I_s = 75A,$	V _{SD}	-	-	1.75	Volts
$V_{GS} = 0V$					
REVERSE RECOVERY TIME $T_J = 25^{\circ}C$					
	t _{rr}	-	300	-	nsec
I _F = 75A, -di/dt = 100A/μsec, V _R = 100V					
INPUT CAPACITANCE $V_{GS} = 0 V$	C _{iss}	-	4500	-	
OUTPUT CAPACITANCE $V_{DS} = 25 V$	C _{oss}		1300		pF
REVERSE TRANSFER CAPACITANCEf = 1.0MHz	C _{rss}		550		

• 221 WEST INDUSTRY COURT • DEER PARK, NY 11729-4681 • PHONE (631) 586-7600 • FAX (631) 242-9798 •
• World Wide Web Site - www.sensitron.com • E-mail Address - sales@sensitron.com •

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MECHANICAL DIMENSIONS: in Inches / mm

LCC-3P

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
N CHANNEL MOSFET IN A	DRAIN	SOURCE	GATE
LCC-3P PACKAGE			

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